

## Switching Transistor

## FM720

## ■ Features

- 625mW power dissipation.
- $I_C$  CONT 2.5A.
- $I_C$  up to 10A peak pulse current.
- Excellent  $h_{fe}$  characteristics up to 10A (pulsed).
- Extremely low saturation voltage e.g. 10mV typ..
- Exhibits extremely low equivalent on-resistance;  $R_{CE(sat)}$  .

■ Absolute Maximum Ratings  $T_a = 25^\circ\text{C}$ 

Parameter	Symbol	Rating	Unit
Collector-base voltage	$V_{CBO}$	-40	V
Collector-emitter voltage	$V_{CEO}$	-40	V
Emitter-base voltage	$V_{EBO}$	-5	V
Peak collector current	$I_{CM}$	-4	A
Collector current	$I_C$	-1.5	A
Base current	$I_B$	-500	mA
Power dissipation	$P_{tot}$	625	mW
Operating and storage temperature range	$T_j, T_{stg}$	-55 to +150	$^\circ\text{C}$

## FMMT720

■ Electrical Characteristics  $T_a = 25^\circ\text{C}$ 

Parameter	Symbol	Testconditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C = -100\mu\text{A}$	-40	-95		V
Collector-emitter breakdown voltage *	$V_{(BR)CEO}$	$I_C = -10\text{mA}$	-40	-85		V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E = -100\mu\text{A}$	-5	-8.8		V
Collector cutoff current	$I_{CBO}$	$V_{CB} = -35\text{V}$			-100	nA
Emitter cut-off current	$I_{EBO}$	$V_{EB} = -4\text{V}$			-100	nA
Collector-emitter saturation voltage *	$V_{CE(sat)}$	$I_C = -0.1\text{A}, I_B = -10\text{mA}$ $I_C = -1\text{A}, I_B = -50\text{mA}$ $I_C = -1.5\text{A}, I_B = -100\text{mA}$		-25 -150 -245	-40 -220 -330	mV
Base-emitter saturation voltage *	$V_{BE(sat)}$	$I_C = -1.5\text{A}, I_B = -75\text{mA}$		0.89	-1	V
Base-emitter voltage *	$V_{BE(ON)}$	$I_C = -1.5\text{A}, V_{CE} = -2\text{V}$		-0.80	-1	V
DC current gain *	$h_{FE}$	$I_C = -10\text{mA}, V_{CE} = -2\text{V}$ $I_C = -0.1\text{A}, V_{CE} = -2\text{V}$ $I_C = -1\text{A}, V_{CE} = -2\text{V}$ $I_C = -1.5\text{A}, V_{CE} = -2\text{V}$ $I_C = -3\text{A}, V_{CE} = -2\text{V}$	300 300 180 60 12	480 450 290 130 22		
Current-gain-bandwidth product	$f_T$	$I_C = -50\text{mA}, V_{CE} = -10\text{V}, f = 100\text{MHz}$	150	190		MHz
Output capacitance	$C_{obo}$	$V_{CB} = -10\text{V}, f = 1\text{MHz}$		19	25	pF
Turn-on time	$t_{(on)}$	$V_{CC} = -10\text{V}, I_C = -1\text{A}$		40		ns
Turn-off time	$t_{(off)}$	$I_{B1} = -I_{B2} = -20\text{mA}$		435		ns

\* Pulse test:  $t_p \leq 300 \mu\text{s}$ ;  $d \leq 0.02$ .

## ■ Marking

Marking	720
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